## Audio Frequency Power Amplifier

## Features

. Low Speed Switching


ORDERING INFORMATION

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SL1002PT SOT-89
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SL1002ET SOT-223

## NPN Epitaxial Silicon Transistor

## Absolute Maximum Ratings $\mathbf{T c}=\mathbf{2 5}^{\circ} \mathrm{C}$ unless otherwise noted

| Symbol | Parameter | Value | Units |
| :--- | :--- | :---: | :---: |
| VCBO | Collector-Base Voltage | 40 | V |
| VCEO | Collector-Emitter Voltage | 30 | V |
| VEBO | Emitter-Base Voltage | 5 | V |
| IC | Collector Current (DC) | 3 | A |
| ICP | *Collector Current (Pulse) | 7 | A |
| IB | Base Current (DC) | 0.6 | A |
| PC | Collector Dissipation | $\left(\mathrm{TC}=25^{\circ} \mathrm{C}\right)$ | 10 |
| R日ja | Junction to Ambient | W |  |
| RӨjc | Junction to Case | 132 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| TJ | Junction Temperature | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |  |
| TSTG | Storage Temperature | 150 | ${ }^{\circ} \mathrm{C}$ |

* PW $\leq 10 \mathrm{~ms}$, Duty Cycle $\leq 50 \%$

Electrical Characteristics $\mathbf{T c}=\mathbf{2 5}{ }^{\circ} \mathrm{C}$ unless otherwise noted

| Characteristics | Symbol | Unit | Measurement Mode | Min | Max |
| :--- | :---: | :---: | :--- | :---: | :---: |
| DC Current Gain (1), (2) | $\mathrm{h}_{\mathrm{FE}}$ |  | $\mathrm{V}_{\mathrm{ce}}=2 \mathrm{~V}, \mathrm{I}_{\mathrm{c}}=20 \mathrm{~mA}$ | 30 |  |
| DC Current Gain (1), (2) | $\mathrm{h}_{\mathrm{FE}}$ |  | $\mathrm{V}_{\mathrm{ce}}=2 \mathrm{~V}, \mathrm{I}_{\mathrm{c}}=1 \mathrm{~A}$ | 60 | 400 |
| Collector Cut-off Current | $\mathrm{I}_{\mathrm{cbo}}$ | $\mu \mathrm{A}$ | $\mathrm{V}_{\mathrm{cb}}=30 \mathrm{~V}, \mathrm{I}_{\mathrm{e}}=0$ |  | 1.0 |
| Collector Cut-off Current | $\mathrm{I}_{\mathrm{cbo}}$ | $\mu \mathrm{A}$ | $\mathrm{V}_{\mathrm{cb}}=40 \mathrm{~V}, \mathrm{I}_{\mathrm{e}}=0$ | 100 |  |
| Emitter Cut-off Current | $\mathrm{I}_{\mathrm{ebo}}$ | $\mu \mathrm{A}$ | $\mathrm{V}_{\mathrm{eb}}=3 \mathrm{~V}, \mathrm{I}_{\mathrm{c}}=0$ | 1.0 |  |
| Emitter Cut-off Current | $\mathrm{I}_{\mathrm{ebo}}$ | $\mu \mathrm{A}$ | $\mathrm{V}_{\mathrm{eb}}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{c}}=0$ |  | 100 |
| Collector-Emitter <br> Saturation Voltage (1) | $\mathrm{V}_{\mathrm{ce} \text { (sat) }}$ | V | $\mathrm{Ic}=2 \mathrm{~A}, \mathrm{Ib}=0.2 \mathrm{~A}$ | 0.5 |  |
|  |  |  |  | 0.1 |  |
| Base-Emitter <br> Saturation Voltage (1) | $\mathrm{V}_{\mathrm{be} \text { (sat) }}$ | V | $\mathrm{IC}=2 \mathrm{~A}, \mathrm{Ib}=0.2 \mathrm{~A}$ |  | 2.0 |

(1) Pulse Test: Pulse Width $\leq 300 \mu \mathrm{~s}$. Duty Cycle $\leq 2 \%$
(2) Measurement mode for a network with common base: $\mathrm{Vcb}=1 \mathrm{~V}$, le=lc

[^0]Typical Characteristics (Continued)


Figure 7. Derating Curve of Safe Operating Areas


Figure 8. Power Derating

## SOT-89-3L PACKAGE OUTLINE DIMENSIONS



| Symbol | Dimensions In Millimeters |  | Dimensions In Inches |  |
| :--- | :--- | :--- | :--- | :--- |
|  | Min | Max | Min | Max |
| A | 1.400 | 1.600 | 0.055 | 0.063 |
| b | 0.320 | 0.520 | 0.013 | 0.020 |
| b1 | 0.360 | 0.560 | 0.014 | 0.022 |
| c | 0.350 | 0.440 | 0.014 | 0.017 |
| D | 4.400 | 4.600 | 0.173 | 0.181 |
| D1 | 1.400 | 1.800 | 0.055 | 0.071 |
| E | 2.300 | 2.600 | 0.091 | 0.102 |
| E1 | 3.940 | 4.250 | 0.155 | 0.167 |
| e1 | 2.900 |  |  | 0.114 |
| L | 0.900 | 1.500 TYP | 0.035 | 0.122 |

## SOT-223




[^0]:    *Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied.
    Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

